

LATCH CIRCUIT

Background of the Invention

5 The invention relates to a latch circuit, and more particularly to a latch circuit suitable for high-speed operation at low supply voltages.

Latch circuits are commonly used circuits, e. g., for memorizing a binary signal, for use in state machines, frequency dividers, counters. Modern technology trends are low-voltage supply for digital circuits for obtaining a relatively lower power consumption of logic families operating at lower and lower supply voltages and down-scaling of the oxide thickness for reliability reasons. When speed is an important feature, the design of digital building blocks may be inspired by analog techniques since any of the classical digital solutions working at low speed do not provide the required performance. The fastest logic family in MOS technology, which is widespread in modern integrated circuits, is the so- called Source Coupled Logic (SCL) family. However, at relatively low supply voltages, e. g., 1.2 V or lower, SCL family does not work properly due to the stacking of transistors, i.e., between a positive supply voltage and ground there are at least three transistors. This category includes AND, OR, XOR gates and the D-latch. The D-latch is relatively difficult function to be implemented because the requirements for a relatively small set-up and hold times are obtained with a relatively high power consumption. When working with signals having a period comparable with the time delay through the latch, the latch requires high gain to operate correctly. However, the transconductance of modern MOS transistors is lower than their bipolar counterparts and therefore larger transistors and higher currents are necessary. As a consequence, the rise and fall times of the digital signals are deteriorated and therefore the operating speed of the circuit is reduced.

US-2003/0001646 describes, among other circuits, a latch circuit as shown in Fig. 6. Fig. 6 shows an SCL triggered D-latch. When CK is positive, the differential pair M1, M2 tracks the input D and on the negative level of the CK the latch M3, M4 becomes active memorizing in a binary format the input signal provided at the D input. This circuit has several disadvantages.

The supply voltage is limited to $V_{GS} + 2(V_{GS} - V_T) + \Delta V$, where V_{GS} is the gate- source voltage of one of the transistors M1... M4, or the MOS current source I_0 , V_T is the threshold voltage of the transistors and ΔV is the voltage drop on the resistor R needed to bias the transistors M1 and M2. In

modern processes like CMOS18 the supply voltage is limited to 1.8V and the circuit should work at 1.62V (1.8V-10%).

The latch and the differential pair share the same load together. Therefore the latch has the difficult task to take decisions on a large capacitance load given by its own stray capacitances the parasitic capacitances of M1 and M2 and the load capacitance given by wiring, fan-in and the resistor R. The use of a buffer between the latch and the gain stage is excluded due to the lack of voltage headroom and the lack of good source-followers in baseline digital processes.

The intrinsic delay between the data path and the clock path. The clock path has a larger delay than the data path and therefore the delay times from CK to Q output ($t_{dCK \rightarrow Q}$) and from D to Q output ($t_{dD \rightarrow Q}$) are not equal. This can impair the function of a phase detector and can generate extra offset in a PLL loop in lock.

The transistors are stacked. Thus the operating level of the Δ and CK signals are different. Level shifting between the D levels and the CK level, needs extra source followers or other level shifters that decrease the speed of operation and increase the delay between the data path and the clock path.

Hence, there is a need to obtain a latch operating at relatively high frequency and using relatively low supply voltages.

Summary

The invention is defined by the independent claims 1 and 10. The dependent claims define advantageous embodiments. It is provided a latch circuit comprising,

a differential input with an inverting input and a non-inverting input,

a differential output with an inverting output and a non-inverting output,

one of said non-inverting outputs being coupled to one of said input, having opposite polarity; and

a control input for receiving a control signal for determining a threshold for an input signal such that if the signal is at larger than the threshold the non-inverting is in a HIGH logic state and in a LOW state if the signal is smaller than the threshold, respectively.

Logical states of a logic circuit as a latch are determined inter alia by the supply voltage. It is defined a threshold level, which may be a current or a voltage, and a signal having a higher amplitude than the threshold level determines a logical 1 signal and a logical 0, otherwise. For a

given family of logic circuits, the threshold level depends on the supply voltage. In order to adapt to a relatively large set of supply voltages i.e. between 3V and. 9 V, a control signal, which determines the threshold level is provided. Furthermore, the latch circuit is adapted to receive single ended signals and provides differential output signals.

It is also provided a latch circuit adapted for differential input signals and comprising a first latch portion and second latch portion, which are substantially identical, each latch portion comprising

a differential input with an inverting input and a non-inverting input,

a differential output with an inverting output and a non-inverting output,

one of the outputs of the first latch portion being coupled to one of the inputs of the second latch portion, having opposite polarity,

one of the outputs of the second latch portion being coupled to one of the inputs of the first latch portion having opposite polarity,

a differential input signal being provided at one of the inputs of the first latch portion and to one of the inputs of the second latch portion having opposite polarity, respectively, and

each of the latch portions comprising a control input, coupled to a respective control signal, which determines a threshold for the input signal such that if the input signal is larger than the threshold the output latch is in a HIGH logic state and in a LOW state if the signal is smaller than the threshold, respectively. In the differential implementation, it is possible to identify a track circuit, which is the first latch portion and a latch, which is the second latch portion. A threshold of the first latch portion and second latch portion is determined by the control signals. Hence a relatively good adaptation to supply voltage is realized. Another advantage of the differential implementation is that it uses identical parts as single ended implementation and therefore the cost of implementation is relatively low and the design process is reduced when compared with the known implementations.

The embodiments refer to implementations in CMOS technology but the inventive concept may be applied mutatis mutandis to other technologies, e. g., GaAs, SiGe.

Brief Description of the Drawings

The above and other features and advantages of the invention will be apparent from the following description of the exemplary embodiments of the invention with reference to the accompanying drawings, in which:

Fig. 1 depicts a block diagram of a latch circuit adapted to single ended input signals, according to an embodiment of the invention ;

Fig. 2 depicts a transistor-level implementation of the latch circuit adapted to single ended input signals, according to an embodiment of the invention;

Fig. 3 depicts a block diagram of a latch circuit adapted to differential input signals, according to an embodiment of the invention;

Fig. 4 depicts a transistor implementation level of a first embodiment of a latch circuit adapted to differential input signals, according to an embodiment of the invention;

Fig. 5 depicts a transistor level implementation of a second embodiment of a latch circuit adapted to differential input signals, according to an embodiment of the invention; and

Fig. 6 depicts a prior-art latch circuit.

Detailed Description

Fig. 1 depicts a block diagram of a latch circuit adapted to single ended input signals, according to the invention. The circuit comprises a differential input with a non-inverting input D+ and an inverting input D-. It is also provided a differential output with a non-inverting output Q+ and an inverting output Q- and a differential clock input with a non-inverting clock input Ck+ and an inverting clock input Ck-.

The inverting output Q- is coupled to the inverting input D+ and the non- inverting input D- is provided for receiving a single ended inverting input signal IN-, which is memorized in the latch. The latch further has a control input for receiving a control signal V_{CM} for determining a threshold for the input signal IN- such that if the signal is at level above the threshold, the output latch is in a HIGH logic state and in a LOW state otherwise. Logical states of a logic circuit are dependent on the supply voltage. Logical states are defined by a threshold level, which may be a current or a voltage, and a signal having an higher amplitude than the threshold level are defined as a logical 1 signal and a logical 0, otherwise. For a given family of logic circuits, the threshold level generally depends on the supply voltage. In order to adapt to a relatively large range of supply voltage, i.e.,

between 3V and 0.9 V, a control signal, which determines the threshold level is provided. Furthermore, the latch circuit can be adapted to receive single ended signals and provides differential output signals.

The latch circuit of Fig. 1 is further described with reference to Fig. 2 depicting a transistor-level implementation of the latch circuit adapted to single ended input signals. The circuit comprises a first pair of transistors, with a first transistor M1 and a second transistor M3 having their sources coupled to each other and a second pair of transistors comprising a third transistor M4 and a fourth transistor M5 having their sources coupled to each other. A gate of the second transistor M3 is coupled to a gate of the third transistor M4 and to the control signal VCM. The inverting output Q- is connected to a gate of the first transistor M1. The circuit further includes a pair of switches comprising a first switch M2 and a second switch M6 having their respective drains and sources coupled to the respective drains and sources of the first transistor M1 and the fourth transistor M5, respectively. Gate of the first switch M2 is driven by the non-inverting clock signal Ck+ and gate of the second switch (M5) is driven by the inverting clock signal Ck-. In the latch circuit shown in Fig. 2 the sources of the first transistor M1 and the second transistor M3 are supplied by a first current source I0 and the sources of the third transistor M4 and the fourth transistor M5 are supplied by a second current source I1. In a preferred embodiment, the first current source (I0) and the second current source I1 provide substantially equal currents and therefore the transistors M1, M2, M3 and M4, M5, M6 share the same current. In the latch circuit the drain of the first transistor M1 and the drain of the fourth transistor M5 are coupled to each other and further coupled to a supply voltage VDD via a first resistor R1. The drain of the second transistor M3 is coupled to a drain of the third transistor M4, the drains being further coupled to the supply voltage VDD via a second resistor R2. The first resistor and the second resistor may have substantially identical values. The second resistor R2 is coupled to a reference terminal GND via a third current source I2. It should be observed that the current sources might be implemented in various ways, e. g., simply resistors, but to increase the overall performance of the latch over a range of temperature the first current source I0 and the second each have a transistor operating as current source in series with a resistor, as shown in Fig. 5. A voltage VC controls the sources. When temperature changes, the resistance of the series resistor changes, the source currents in the latch stages are adjusted accordingly in order to ensure a correct operation over a large temperature range.

Referring to Fig. 2, in a tracking-mode, the non-inverting clock CK+ is HIGH, the inverting clock CK- is LOW and the transistors M4 and M5 act as a differential pair sharing the current I_ϕ whereas M6 is in cut-off, i.e., a negligible current passes through it. The signal received at the inverting input D- is amplified at the non-inverting output Q+ and inverting output Q-. Accordingly, the transistor M2 gets the whole current I_ϕ forcing the transistors M1 and M3 to cut off. The amplitude of the clock CK+ is sufficiently high to substantially avoid any leakage current from M1 and M3. The voltage VCM provides a threshold for the input data in tracking mode and for the latch in a latching mode.

In the latching mode, the inverting clock CK- is asserted LOW, the non-inverted clock CK+ is asserted HIGH and the transistor M6 takes the whole current I_1 . As a consequence, the transistors M4 and M5 are in cut-off. The transistor M2 is also in cut-off and the transistors M1 and M3 are active and the data is transferred from the input to the output and it is memorized. This is a relatively fast circuit since the amplifying loop is a source follower M1 and a cascode transistor M3, having a relatively large bandwidth.

Table 1 shows the switching table of the latch with the analog values presented at the two outputs. The current source at the output I2 has the role of generating a differential operation with a swing of RI_0 , where $I_0=I_1=I_0$.

D+	CK+	Q+[n]	Q+[n+1]	Q-[n+1]
0	0	0	$V_{DD}-2RI_0$	$V_{DD}-RI_0$
0	0	1	$V_{DD}-RI_0$	$V_{DD}-2RI_0$
0	1	0	$V_{DD}-2RI_0$	$V_{DD}-RI_0$
0	1	1	$V_{DD}-2RI_0$	$V_{DD}-RI_0$
1	0	0	$V_{DD}-2RI_0$	$V_{DD}-RI_0$
1	0	1	$V_{DD}-RI_0$	$V_{DD}-2RI_0$
1	1	0	$V_{DD}-RI_0$	$V_{DD}-2RI_0$
1	1	1	$V_{DD}-RI_0$	$V_{DD}-2RI_0$

Table 1

In Table 1 it was considered that all current sources deliver the same current I_0 . Furthermore, all resistors have the same resistance R.

Since the input is not a differential input we can extend the basic circuit to a differential input, differential output circuit with some extra advantages compared to the simple basic idea. An embodiment of the invention with differential input and differential output is shown in Figs. 3 and 4.

Fig. 3 depicts a block diagram of a latch circuit adapted to differential input signals. The latch circuit is adapted for differential input signals $In+$, $In-$ and comprises a first latch portion 1' and second latch portion 1'', which are substantially identical. Each latch portion comprises a differential input with a non-inverting input $D1+$, $D2+$ and an inverting input $D1-$, $D2-$, a differential output with a non-inverting output $Q1+$, $Q2+$ and an inverting output $Q1-$, $Q2-$ and a differential clock input with a non-inverting clock input $Ck1+$, $Ck2+$ and an inverting clock input $Ck1-$, $Ck2-$. The non-inverting clock inputs are coupled to each other and are further coupled to a non-inverting clock signal $Ck+$ and the inverting clock inputs being coupled to each other and being further coupled to an inverting clock signal $Ck-$. The inverting output $Q1-$ of the first latch portion 1' is coupled to the non-inverting input ($D2+$) of the second latch portion (1''). The non-inverting output $Q2+$ of the second latch portion being coupled to the inverting input of the first latch portion $D1-$. A differential input signal $In+$, $In-$ is provided at the inverting input of the first latch portion 1' and to the inverting input of the second latch portion 1'', respectively, and each of the latch portions has a control input V_{CM1} , V_{CM2} , which is coupled a respective control signal V_{CM1} , V_{CM2} , which determines a threshold for the input signal $In+$, $In-$ such that if the signal is larger than the threshold the signal is in a HIGH logic state and in a LOW state, otherwise. In the differential implementation, it is possible to identify a track circuit, which is the first latch portion 1' and a latch, which is the second latch portion 1''. A threshold of the first latch portion 1' and second latch portion 1'' is determined by the control signals V_{CM1} , V_{CM2} . Hence, a relatively good adaptation to supply voltage VDD to the threshold voltages of the latch circuit is realized. Another advantage of the differential implementation is that it uses identical parts as single ended implementation and therefore the cost of implementation is relatively low and the design process is reduced.

Fig. 4 depicts a transistor level schematic of a latch circuit adapted to differential input signals, . The latch circuit comprises transistors, each transistor having a source, a gate and a drain, and wherein each latch portion 1' ; 1'' comprises a first pair of transistors comprising a first transistor $M1A$; $M1B$ and a second transistor $M3A$; $M3B$, having their sources coupled to each

other, respectively. The latch circuit further comprises a second pair of transistors comprising a third transistor M4A; M4B and a fourth transistor M5A; M5B, having their sources coupled to each other, respectively. A gate of the second transistor M3A; M3B is coupled to a gate of the third transistor M4A; M4B respectively and further coupled to a DC voltage level V_{CM} . In this particular implementation, the control signals V_{CM1} , V_{CM2} are equal to each other and further equal to V_{CM} . A pair of switches comprising a first switch M2A; M2B and a second switch M6A; M6B, the switches including transistors having their respective drains and sources coupled to the respective drains and sources of the first transistor M1A; M1B and the fourth transistor M5A; M5B, respectively, is also provided. The gate of the first switch M2A; M2B is driven by a binary clock signal $Ck+$ and gate of the second switch M6A; M6B being driven by an inverted binary clock signal $Ck-$. The two latch portions 1', 1" are crossed-coupled such that a gate of the first transistor M1A; M1B of a portion is coupled to the respective output of the other portion $INTQ-$; $INTQ+$, respectively.

The sources of the first transistor M1A, M1B and the second transistor M3A, M3B are supplied by a first current source $I0A$, $I0B$. The sources of the third transistor M4A, M4B and the fourth transistor M5A, M5B are supplied by a second current source $I1A$, $I1B$. Particularly, the current sources deliver substantially equal currents.

The drain of the first transistor M1A ;M1B and the drain of the fourth transistor M5A ; M5B are coupled to each other respectively and further coupled to a supply voltage V_{DD} via a resistor $R1A$, $R1B$. The drain of the second transistor M3A; M3B is coupled to a drain of the third transistor M4A; M4B, respectively, the drains being further coupled to the supply voltage V_{DD} via a second resistor $R2A$, $R2B$.

In the tracking-mode, the non-inverting clock $CK+$ is HIGH asserted, and consequently the inverting clock $Ck-$ is LOW asserted, and the $D+$, $D-$ input voltages are amplified at the internal nodes $INTQ-$ and $INTQ+$ and $Q+$, $Q-$ respectively. Since M2A and M2B are conducting, the latch is in cut-off and no latching action is possible. In the latching mode, the inverting clock $CK-$ is HIGH asserted, and consequently the non-inverting clock $CK+$ is LOW asserted. The transistors M2A and M2B are cut-off now. The information from the $D+$, $D-$ inputs is not passed at the outputs. The transistors M6A and M6B are active now and the information present at the internal nodes A and B is latched. Regarding Fig. 4, it is observed that data has two paths: a path to the output via the common-source, common-gate configurations M5A, M5B and M4A, M4B respectively and a path

to the internal nodes INTQ+ and INTQ- via common source transistors M5A and M5B. Hence, the latch and the gain stages may be optimized separately using different loads for the latch R1 and the output R2. Moreover, when the latch is taking decisions at the outputs A and B the transistors M6A and M6B are active and the information present at the nodes A and B is amplified at the outputs Q+, Q- with a high speed provided by stages M1A, M3A and M1B, M3B. This reduces setup and hold times.

Fig. 5 depicts a transistor level schematic of a second embodiment of a latch circuit adapted to differential input signals. The first current source I0 and the second current source I1 comprises a series connection of a main current channel of a controlled current source M13A, M14A, M13B, M14B and resistors R3A, R4A, R3B, R4B. A voltage VC controls the controlled sources M13A, M14A, M13B, M14B. It should be observed that the current sources might be implemented in various ways as, e. g., simply resistors, but to increase the overall performance of the latch versus temperature the first current source I0 and the second current source I1 comprise a series connection as described above. When temperature changes, the resistance of the resistors R3A, R4A, R3B, R4B changes and therefore the source currents in the latch stages are adjusted accordingly in order to ensure a correct operation over a large temperature range.

It is remarked that the scope of protection of the invention is not restricted to the embodiments described herein. Neither is the scope of protection of the invention restricted by the reference numerals in the claims. The word 'comprising' does not exclude other parts than those mentioned in the claims. The word 'a (n)' preceding an element does not exclude a plurality of those elements. Means forming part of the invention may both be implemented in the form of dedicated hardware or in the form of a programmed purpose processor. The invention resides in each new feature or combination of features.

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